TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSIV)

TPCC8008

Notebook PC Applications Portable Equipment Applications

- · Small footprint due to a small and thin package
- Low drain-source ON-resistance:

 $R_{DS (ON)} = 4.5 \text{ m}\Omega \text{ (typ.) (}V_{GS} = 10 \text{ V)}$

- Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 30 \text{ V)}$
- Enhancement mode: V_{th} = 1.3 to 2.5 V (V_{DS} = 10 V, I_D = 1.0 mA)

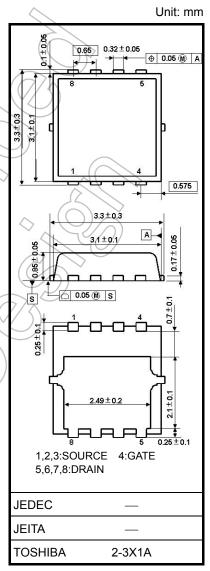
Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	30	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	30	> V
Gate-source voltage		V_{GSS}	±25	V
Drain current	DC (Note 1)	ΙD	25	Α
	Pulsed (Note 1)	I _{DP}	75	
Drain power dissipation	on (Tc = 25°C)	PD	30	<\w
Drain power dissipation (t = 10 s) (Note 2a)		PD	1.9	w
Drain power dissipation	on (t = 10 s) (Note 2b)	PD	0.7	/w
Single-pulse avalanch	ne energy (Note 3)	EAS	163	mJ
Avalanche current		1 _{AR}	25/	Α
Repetitive avalanche (To	energy = 25°C) (Note 4)	E _{AR}	2.58	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

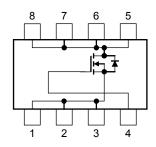
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.02 g (typ.)

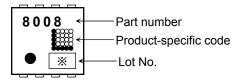
Circuit Configuration



Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R _{th (ch-c)}	4.2	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	66	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	180	°C/W

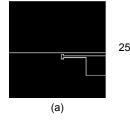
Marking (Note 5)

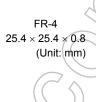


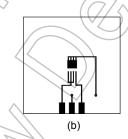
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)







FR-4 $25.4 \times 25.4 \times 0.8$ (Unit: mm)

Note 3: $V_{DD} = 24 \text{ V}$, $T_{Ch} = 25^{\circ}\text{C}$ (initial), $L = 200 \text{ }\mu\text{H}$, $R_G = 25 \Omega$, $I_{AR} = 25 \text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: * Weekly code: (Three digits)

Week of manufacture

(01 for the first week of the year, continuing up to 52 or 53)

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Year of manufacture (The last digit of the year)

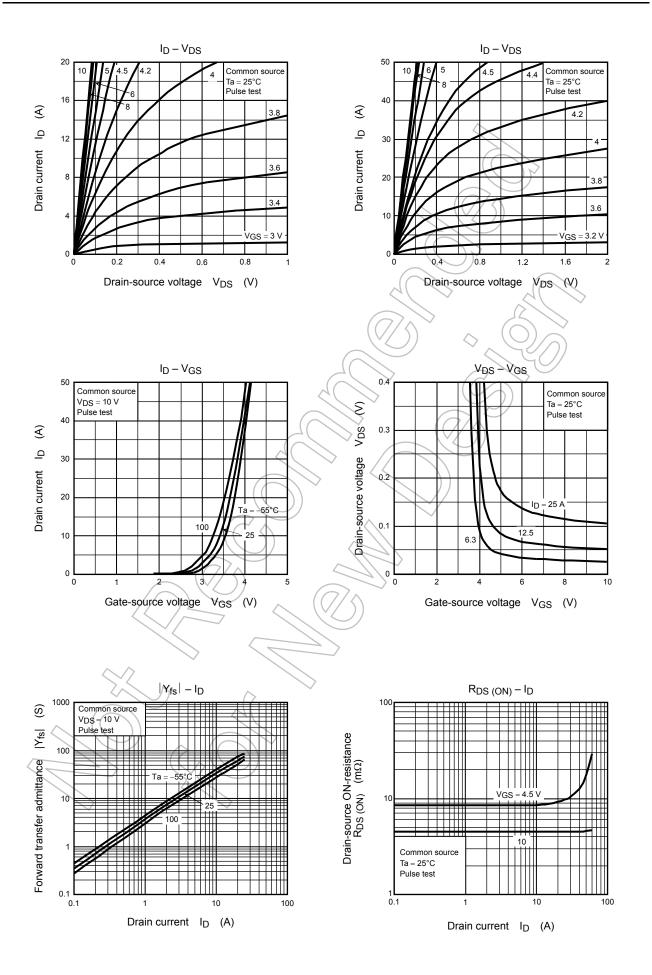
Electrical Characteristics (Ta = 25°C)

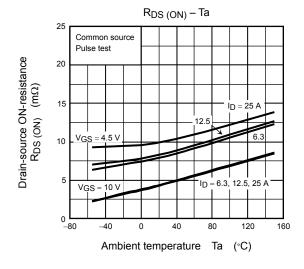
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA	
Drain cutoff curre	ent	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_	_	10	μА	
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	V	
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	15		_		
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, I_D = 1.0 \text{ mA}$	1.3) /_	2.5	V	
Drain-source ON-resistance		Б	V _{GS} = 4.5 V, I _D = 12.5 A		8.5	13	- mΩ	
		R _{DS} (ON)	V _{GS} = 10 V, I _D = 12.5 A))	4.5	6.8		
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 12.5 A	22	43	_	S	
Input capacitance		C _{iss}		_	1600	_		
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	290	_	pF	
Output capacitan	се	Coss			470	\searrow		
Switching time	Rise time	t _r	V _{GS} 10 V I _D = 12.5 A O V _{OUT} C _S C _S	10 V D In = 12.5 A	> —			
	Turn-on time	t _{on}			15	_		
	Fall time	t _f	R = 1.25	(\mathcal{E})	16	_	ns	
	Turn-off time	t _{off}	V _{DD} ≈ 15 V Duty ≤ 1%, t _W = 10 μs) —	42	_		
Total gate charge (gate-source plus		Qg		_	30	_		
Gate-source char	rge 1	Q _{gs1}	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$		5.9		nC	
Gate-drain ("Miller") charge		Q _{gd}		_	9.6			

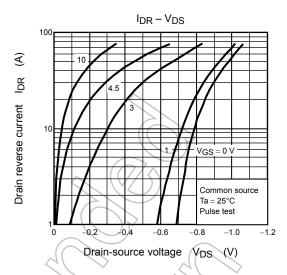
Source-Drain Ratings and Characteristics (Ta = 25°C)

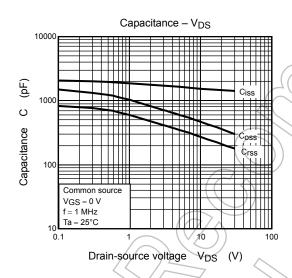
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	I _{DRP}	<u> </u>	_	_	75	Α
Forward voltage (diode)	V _{DSF}	$I_{DR} = 25 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.2	V

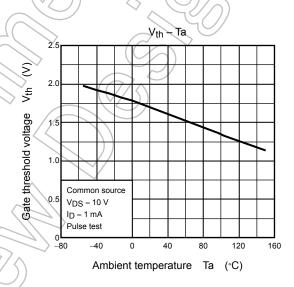
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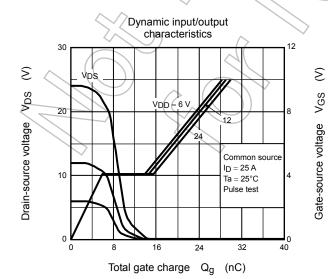




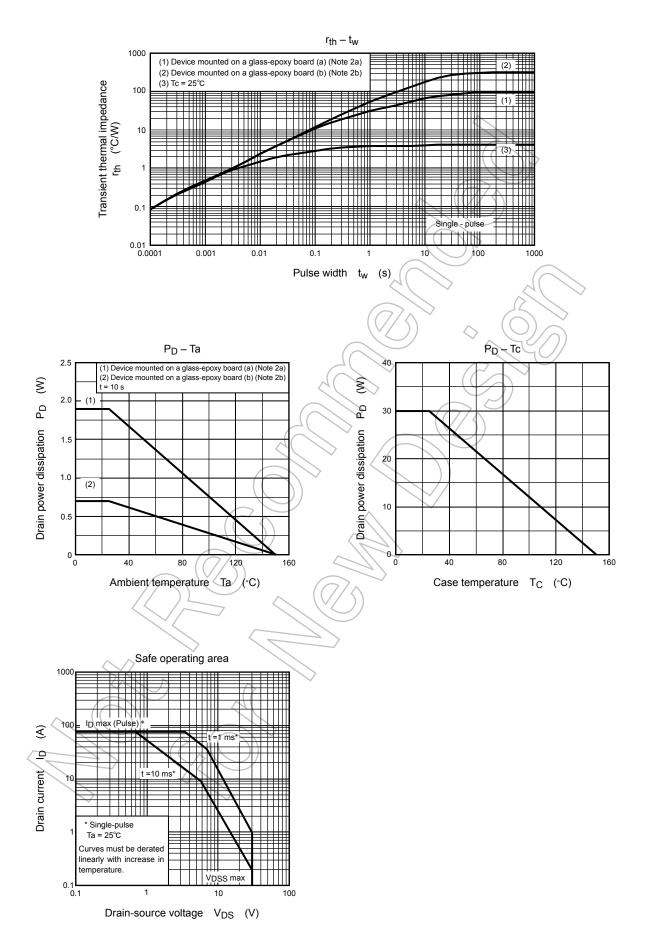








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